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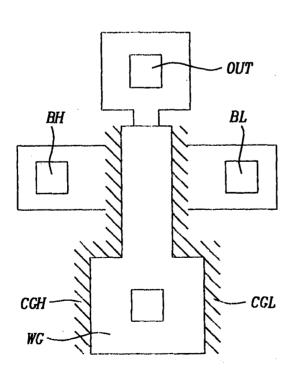
(57) Abstract:

[Continued on next page]

nonvolatile

Α

(54) Title: TRAP-CHARGE NON-VOLATILE SWITCH CONNECTOR FOR PROGRAMMABLE LOGIC



trap charge storage cell selects a logic interconnect transistor uses in programmable logic applications, such as FPGA. The nonvolatile trap charge element is an insulator located under a control gate and above an oxide on the surface of a semiconductor substrate. The preferred embodiment is an integrated device comprising a word gate portion sandwiched between two nonvolatile trap charge storage portions, wherein the integrated device is connected between a high bias, a low bias and an output. The output is formed by a diffusion connecting to the channel directly under the word gate portion. The program state of the two storage portions determines whether the high bias or the low bias is coupled to a logic interconnect transistor connected to the output diffusion.



WO 2008/057371 A3



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Declarations under Rule 4.17:

- as to applicant's entitlement to apply for and be granted a patent (Rule 4.17(ii))
- as to the applicant's entitlement to claim the priority of the earlier application (Rule 4.17(iii))
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According to International Patent Classification (IPC) or to both national classification and IPC			
B. FIELDS SEARCHED			
Minimum documentation searched (classification system followed by classification symbols) USPC: 711/101			
Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched USPC: 711/100, 101, 105, 154, 170, 710/8, 12, 22, 64, 73			
Electronic data base consulted during the international search (name of data base and, where practicable, search terms used) USPTO WEST (PGPB, USPT, EPAB, JPAB); Google Scholar Search terms: memory or storage or nonvolatile, trap charge, transistor connected in series, switch connector, word gate, logic element or array, p channel transistor, tunnel, programmable logic, switch on or off etc.			
C. DOCUMENTS CONSIDERED TO BE RELEVANT			
Category*	Citation of document, with indication, where app	propriate, of the relevant passages	Relevant to claim No.
X	US 6,788,111 B2 (SUN et al.) 07 September 2004 (07.0 In 10-43, col 4, In 21-64, col 6, In 11 to col 7, In 48	9.2004), abstract, Fig 2A, 2B, 3, col 2,	1-25
A ·	US 2005/0219900 A1 (KAMIGAKI et al.) 06 October 2005 (06.10.2005)		1-25
Α	US 2005/0201189 A1 (FUJIWARA et al.) 15 September 2005 (15.09.2005)		1-25
A	US 2005/0012134 A1 (MASUOKA et al.) 20 June 2005 (20.06.2005)		1-25
А	US 2001/0019151 A1 (CAYWOOD) 06 September 2001 (06.09.2001)		1-25
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